## NSN 5961-01-332-1147

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-1147 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 15.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes collector current, dc peak **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-collector major **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release 6741b professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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